Thermal activation and ac-field-induced discontinuous domain jumps in perovskite $La_{0.7}Ca_{0.3}MnO_3$

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Low-field ac susceptibility was measured on bulk $La_{0.7}Ca_{0.3}MnO_3$ prepared by a partial melting technique. Discontinuous jumps with heights of $(1-2)\times10^{-5}$ emu at temperature intervals of 3–5 K were observed in the ac susceptibility. 28 jumps were observed in the temperature range between 4.2 K and the Curie temperature of 250 K, with an ac field amplitude of 1 Oe, a frequency of 117 Hz, and a dc bias field of 5 and 20 Oe. Upon increasing the frequency up to 5000 Hz, the jumps shifted to lower temperature. For a dc bias field of 50 Oe and an ac field with an amplitude of 0.1 Oe and a frequency between 117 and 5000 Hz, only three jumps with heights of about 3×10^{-5} emu at large temperature intervals of about 60 K were observed for $T < T_c$. With increasing frequencies, the three jumps shifted to lower temperatures without changing jump height. The discontinuous jumps in La_{0.7}Ca_{0.3}MnO₃ were interpreted in terms of thermally and ac-field-activated domainwall jumps. [S0163-1829(98)00629-8]

Recently, the discovery of the colossal magnetoresistance (CMR) effect in perovskite-type manganese oxides $La_{1-x}A_xMnO_3$ (LMO) with $A=Ca$, Sr, Ba has attracted much interest as potential applications in magnetic recording and sensors. $1-3$ The Curie temperature can easily be varied by controlling doping levels and can reach 360 K for Sr doped LMO. It was observed that the occurrence of CMR at the Curie temperature with application of magnetic field is accompanied by large lattice distortion for the doped manganites, 4 and magnetostriction was also observed in the CMR compounds.⁵ Much attention has been paid to bulk magnetization, CMR behavior, and structural properties. Since the magnetic domain behavior is a key factor for the applications, the study of domains at different external fields is very desirable. The observation of domains in La-Ca-Mn-O thin films was made by magnetic force microscopy (MFM).⁶ It was found that the domains were very stable at low temperatures in low dc field. We studied the ac susceptibility with various amplitudes of fields and frequencies, with a bias dc field. We report discontinuous jumps in the ac susceptibility for $La_{0.7}Ca_{0.3}MnO_3$ which are due to domain-wall jumps activated by thermal excitation and ac field.

High-purity powders of La_2O_3 , CaCO₃, and MnCO₃ were weighed according to the nominal composition of $La_{0.7}Ca_{0.3}MnO₃$. After a thorough mixing, the powders were pressed into pellets of 10 mm in diameter. The pellets were first sintered at temperature of 1100 °C for 24 h, grinded into powders, pressed into pellets again, then partially melted at 1600 °C and rapidly cooled down to 900 °C with air quenching for achieving high density. After sintering in air, the samples were annealed in O_2 at 600 °C for 24 h. X-ray powder diffraction results indicated a nearly single phase for the partially melted sample. Spherical fine particles of $CaMnO₃$ were also observed. Magnetization and ac susceptibility was measured between 4.2 K and room temperature using a Quantum Design physical property measurement system. ac susceptibility was obtained with an ac field of amplitude of 0.1 and 1 Oe and frequencies of 117, 500, 2000, and 5000 Hz, in the dc bias fields of 5, 20, and 50 Oe.

Figure 1 shows the real part of magnetic susceptibility (χ') vs temperature for a dc field (H_{dc}) of 50 Oe, the amplitude of an ac field (H_{ac}) of 0.1 Oe and frequencies of 117 and 2000 Hz. It is clearly seen that a ferromagnetic transition occurs at 250 K. In addition to this, there are two jumps in χ' for $f = 117$ Hz (inset to Fig. 1). The higher the frequency, the lower the temperature at which these jumps appear. Another jump appeared just below the sharp transition for *f* $=2000$ Hz. These three jumps have heights of about 3 $\times 10^{-5}$ emu with a temperature interval of 60 K. Figure 2 shows χ' vs temperature for H_{dc} =20 Oe, H_{ac} =1 Oe, and $f = 117$ Hz. There is 28 jumps in χ' with heights of 1-2 $\times 10^{-5}$ emu, at temperature intervals of 3–5 K. The jumps seem to be superimposed to the main, smooth χ' vs *T* curve, which can be obtained by connecting χ' vs *T* for T < 42 K with the beginning of each of the jumps (dashed line in Fig. 2). The temperature at which the jumps appear depends on the frequency in qualitatively the same way as for H_{dc} $=$ 50 Oe (inset to Fig. 2), although this dependence is about half as strong as for H_{dc} =50 Oe (Fig. 1). Lowering H_{dc} to 5 Oe, the ac susceptibility vs temperature exhibited the same behavior as that for 20 Oe. The number of the jumps and temperature at which they appear do not change. However, the value of χ' is a bit smaller than for H_{dc} =20 Oe, as shown in Fig. 3. For all these measurements, the jumps in χ' were not accompanied by any features in the imaginary part (χ'') of ac susceptibility.

The jumps in χ' seem to be a thermally activated phenomenon, helped by the magnetic field. While the dc field has a strong influence defining the number of the jumps (Figs. 1 and 2), the ac field excites the system in addition to thermal excitations. We suggest that the jumps in χ' occur because of the releasing of domain walls from pinning centers under a combined influence of the dc field, thermal excitations, and the ac field. Applying a large dc field, only the strongest pinning centers in the sample are effective in pinning the domain walls,⁷⁻¹⁰ giving only two jumps in χ' vs *T* $(Fig. 1)$. For smaller fields, the number of effective pinning sites is increased, giving a large number of jumps $(Fig. 2)$.

f = 117 Hz

 $f = 2000$ Hz

Susceptibility [emu] $7.5x10$ $\overline{100}$ 150 $\overline{200}$ $\overline{25}c$ 0.0 Temperature [K] 50 100 150 200 250 300 $\mathbf 0$ Temperature [K]

FIG. 1. Real part of magnetic susceptibility χ' vs temperature for a dc field of 50 Oe, an amplitude of the ac field of 0.1 Oe, and frequencies of 117 and 2000 Hz. The inset shows two jumps in χ' shift to low temperature with increasing frequency.

The amplitude of the ac field is not large enough to release pinned domain walls. It merely shakes within the potential well.

 $1.0x10^{-3}$

 $8.0x10^{-4}$

 $6.0x10^{-4}$

4.0x10

 $2.0x10$

 $9.5x10$

 $9.0x10$

8.5x10

8.0x10

Susceptibility [emu]

The energy of thermal excitation is proportional to temperature (*T*):

$$
E_t = kT,\t\t(1)
$$

whereas the energy of the excitation by the harmonic ac field is proportional to the square of its frequency (*f*):

$$
E_{ac} = cf^2.
$$
 (2)

Domain walls get released from pinning centers when the pinning energy (E_p) is equal to the combined energy of dc field (E_{dc}) , thermal, and ac field excitations:

$$
E_p = E_{dc} + E_t + E_{ac}.
$$
 (3)

Combining Eqs. (1) – (3) , one obtains

$$
kT + cf^2 = E_p - E_{dc}.
$$
 (4)

For a constant dc field, Eq. (4) gives the temperature at which the domain walls get released from pinning centers:

$$
T_0 = \alpha - \beta f^2,\tag{5}
$$

where $\alpha = (E_p - E_{dc})/k$ and $\beta = c/k$.

Scanning electron microscopy (SEM) and energy dispersive analysis (EDA) observations of our samples revealed spherical fine particles of CaMnO₃ (about 1 μ m in diameter).

FIG. 2. χ' vs temperature for $H_{\text{dc}}=20 \text{ Oe}$, $H_{\text{ac}}=1 \text{ Oe}$, and $f=117 \text{ Hz}$. The inset shows that the temperature at which the jumps appear depends on the frequency in qualitatively the same way as for H_{dc} =50 Oe (inset to Fig. 2),

FIG. 3. χ' vs temperature for H_{dc} =5 Oe (open circle) and H_{dc} =20 Oe (line) with H_{ac} =1 Oe and f =117 Hz.

These particles are probably responsible for the domain-wall pinning and the observed jumps in χ' . If there was no pinning centers in the sample, the domain walls would under the influence of external field take an equilibrium position with minimum energy. With pinning centers, domain walls are pinned in different positions and the field exerts a pressure on them tending to shift them into equilibrium position. The further away they are from the equilibrium position, the larger the pressure is. However, pinned domain walls can still move within the potential well of pinning centers. The smaller the pressure by the field, the larger the mobility of domain walls in the potential well.

When a domain wall gets released from a pinning site under the combined influence of the dc field, thermal excitations, and the ac field, it will jump to a new stable position.^{7–9} In the new position, it will experience a smaller pressure due to the dc field than in the old position, \prime resulting in an increased mobility of the domain wall in the new position. Since the increased mobility gives larger in-phase ac susceptibility, jumps in χ' will occur at a temperature at

FIG. 4. Plot of the temperature of the first jump in Fig. 1 as a function of frequency. The solid line is a fit using Eq. (5) .

which the domain walls jump to new pinning sites. Jumping back to old sites will not occur because the pressure on the domain walls due to the dc field pushes them in one direction only, unlike the dc and thermal excitations. We stress that the measured jumps in χ' will not be accompanied by jumps in χ'' . This is because after the jump, the domain walls only oscillate in new potential wells, which is a reversible process. They do not have enough energy to jump continuously between the pinning sites. The energy loss due to the single jump from old to new pinning sites is not measured in our experiment because the susceptibility is measured at fixed temperature intervals, averaged over several seconds, while the jumps occur in a much shorter time. A peak in χ'' would be obtained, however, if the measurement was performed in that short time, during the jump. Our measuring system cannot detect such fast events. The number of jumps in our experiment is not an intrinsic property of the material. It depends on the distribution and strength of the pinning centers in the sample.

If our model is correct, the jumps in χ' vs temperature should occur at T_0 in Eq. (5) . To check this, we plot the temperature of the first jump in Fig. 1 as a function of frequency $(Fig. 4)$. The solid line is a fit using Eq. (5) . Apparently, our data show very good agreement with Eq. (5) , giving α = 107 K and β =1.9×10⁻⁶ K/Hz². The jump at higher temperature in Fig. 1 gives α =164 K and β =1.48 $\times 10^{-6}$ K/Hz².

In conclusion, we showed that the observed jumps in χ' vs *T* occur because of the thermal excitation of the system, combined with the harmonic excitation of the ac field. We suggested that they appear when domain walls get released from pinning centers under these excitations, resulting in a sudden increase of their mobility.

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